

BF861A; BF861B; BF861C

N-channel junction FETs

Rev. 5 — 15 September 2011

Product data sheet

1. Product profile

1.1 General description

N-channel symmetrical junction field effect transistors in a SOT23 package.

CAUTION



The device is supplied in an antistatic package. The gate-source input must be protected against static discharge during transport or handling.

1.2 Features and benefits

- High transfer admittance
- Low feedback capacitance
- Low input capacitance
- Low noise.

1.3 Applications

Preamplifiers for AM tuners in car radios.

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DS}	drain-source voltage (DC)		-	-	25	V
I _{DSS}	drain current					
	BF861A	$V_{GS} = 0 \text{ V}; V_{DS} = 8 \text{ V}$	2	-	6.5	mA
	BF861B	$V_{GS} = 0 \text{ V}; V_{DS} = 8 \text{ V}$	6	-	15	mA
	BF861C	$V_{GS} = 0 \text{ V}; V_{DS} = 8 \text{ V}$	12	-	25	mA
P _{tot}	total power dissipation	up to T _{amb} = 25 °C	-	-	250	mW
y _{fs}	forward transfer admittance;					
	BF861A	$V_{GS} = 0 \text{ V}; V_{DS} = 8 \text{ V}$	12	-	20	mS
	BF861B	$V_{GS} = 0 \text{ V}; V_{DS} = 8 \text{ V}$	16	-	25	mS
	BF861C	$V_{GS} = 0 \text{ V}; V_{DS} = 8 \text{ V}$	20	-	30	mS
C _{iss}	input capacitance	f = 1 MHz	-	-	10	pF
C _{rss}	reverse transfer capacitance	f = 1 MHz	-	-	2.7	pF



2. Pinning information

Table 2. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	source		
2	drain		3 - 2
3	gate	1 2	sym053

3. Ordering information

Table 3. Ordering information

Туре	Package				
number	Name	Description	Version		
BF861A	-	plastic surface mounted package; 3 leads	SOT23		
BF861B	-	plastic surface mounted package; 3 leads	SOT23		
BF861C	-	plastic surface mounted package; 3 leads	SOT23		

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BF861A	28*
BF861B	29*
BF861C	30*

^{[1] * =} p: Made in Hong Kong.

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

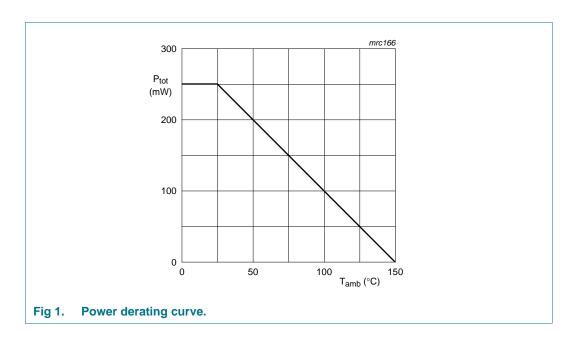
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage (DC)		-	25	V
V_{GSO}	gate-source voltage	open drain	-	25	V
V_{DGO}	drain-gate voltage (DC)	open source	-	25	V
I _G	forward gate current (DC)		-	10	mA
P _{tot}	total power dissipation	up to T _{amb} = 25 °C	[1] -	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	operating junction temperature		-	150	°C

^[1] Device mounted on an FR4 printed-circuit board.

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^{* =} t: Made in Malaysia.

^{* =} W: Made in China.



6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> 500	K/W

^[1] Device mounted on an FR4 printed-circuit board.

7. Characteristics

Table 7. Characteristics

 $T_j = 25$ °C; $V_{DS} = 8$ V; $V_{GS} = 0$ V unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)GSS}$	gate-source breakdown voltage	$I_G = -1 \mu A$	-25	-	-	V
V _{GSoff}	gate-source cut-off voltage					
	BF861A	I _D = 1 μA	-0.2	-	-1	V
	BF861B	$I_D = 1 \mu A$	-0.5	-	-1.5	V
	BF861C	$I_D = 1 \mu A$	-0.8	-	-2	V
V_{GSS}	gate-source forward voltage	$V_{DS} = 0 \text{ V}; I_G = 1 \text{ mA}$	-	-	1	V
I _{DSS}	drain current					
	BF861A		2	-	6.5	mA
	BF861B		6	-	15	mA
	BF861C		12	-	25	mA
I _{GSS}	gate cut-off current	$V_{GS} = -20 \text{ V};$ $V_{DS} = 0 \text{ V}$	-	-	-1	nA

BF861A_BF861B_BF861C

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 Table 7.
 Characteristics ...continued

 $T_i = 25$ °C; $V_{DS} = 8$ V; $V_{GS} = 0$ V unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
y _{fs}	forward transfer admittance					
	BF861A		12	-	20	mS
	BF861B		16	-	25	mS
	BF861C		20	-	30	mS
g _{os}	common source output conductance					
	BF861A		-	-	200	μS
	BF861B		-	-	250	μS
	BF861C		-	-	300	μS
C _{iss}	input capacitance	f = 1 MHz	-	-	10	pF
C _{rss}	reverse transfer capacitance	f = 1 MHz	-	2.1	2.7	pF
V_n/\sqrt{B}	equivalent input noise voltage	$V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}$	-	1.5	-	nV/√Hz

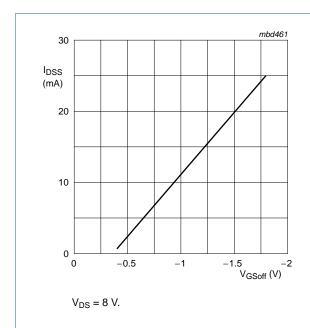


Fig 2. Drain current as a function of gate-source cut-off voltage; typical values.

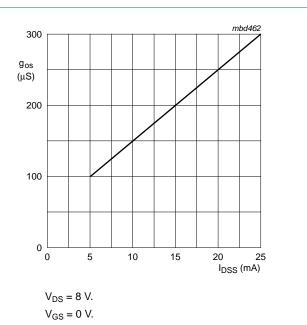


Fig 3. Common-source output conductance as a function of drain current; typical values.

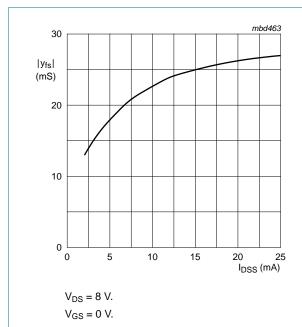


Fig 4. Forward transfer admittance as a function of drain current; typical values.

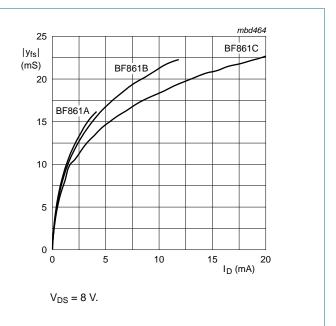


Fig 5. Forward transfer admittance as a function of drain current; typical values.

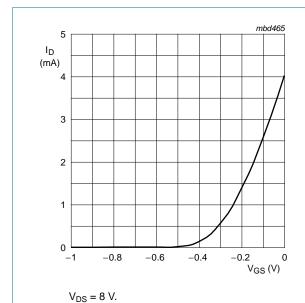
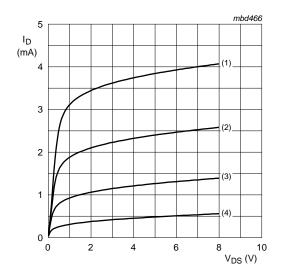


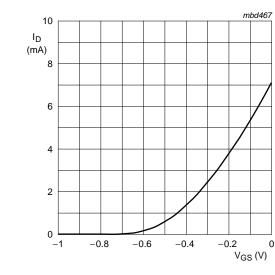
Fig 6. Typical input characteristics; BF861A.



 $V_{DS} = 8 V.$

- (1) $V_{GS} = 0 V$.
- (2) $V_{GS} = -100 \text{ mV}.$
- (3) $V_{GS} = -200 \text{ mV}.$
- (4) $V_{GS} = -300 \text{ mV}.$

Fig 7. Typical output characteristics: BF861A.

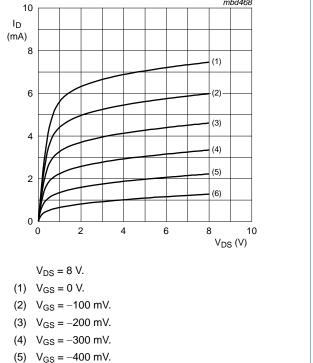




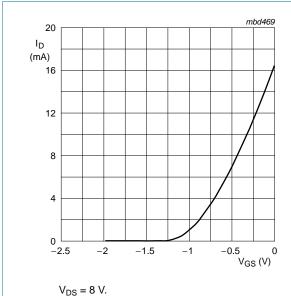
(6) $V_{GS} = -500 \text{ mV}.$

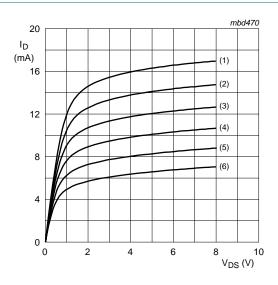
Fig 9.





Typical output characteristics; BF861B.





 $V_{DS} = 8 V.$

(1) $V_{GS} = 0 \text{ V}.$

(2) $V_{GS} = -200 \text{ mV}.$

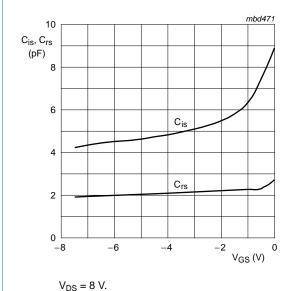
(3) $V_{GS} = -400 \text{ mV}.$

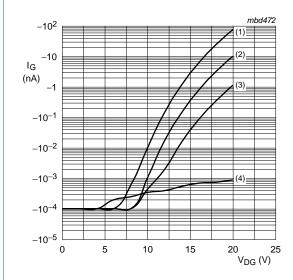
(4) $V_{GS} = -600 \text{ mV}.$

(5) $V_{GS} = -800 \text{ mV}.$ (6) $V_{GS} = -1 \text{ V}.$

Fig 10. Typical input characteristics; BF861C.







 $V_{DS} = 8 \text{ V}.$

(1) $I_D = 10 \text{ mA}.$

(2) $I_D = 1 \text{ mA}$.

(3) $I_D = 0.1 \text{ mA}.$

(4) $I_D = I_{GSS}$.

Fig 12. Input and reverse transfer capacitance as functions of gate-source voltage; typical values.

Fig 13. Gate current as a function of drain-gate voltage; typical values.

f = 1 MHz.

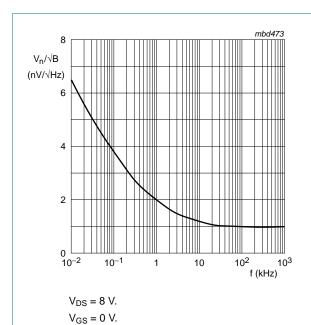


Fig 14. Equivalent input noise as a function of frequency; typical values.

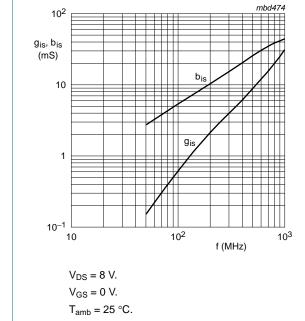
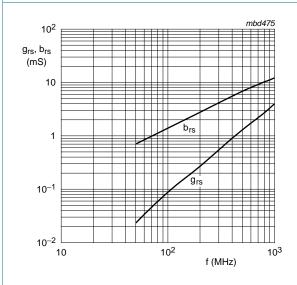


Fig 15. Common-source input admittance; typical values.

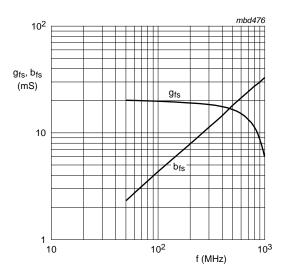


 $V_{DS} = 8 V.$

 $V_{GS} = 0 V.$

 $T_{amb} = 25 \, ^{\circ}C.$

Fig 16. Common-source reverse admittance; typical values.

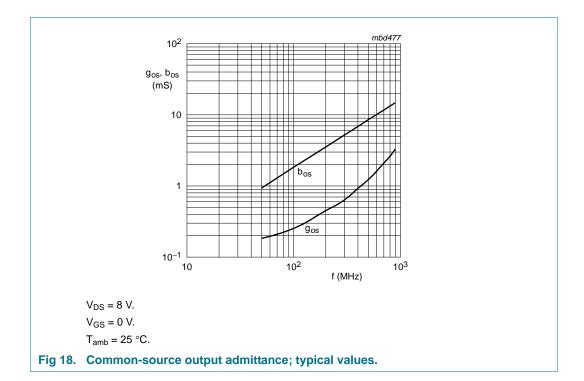


 $V_{DS} = 8 V.$

 $V_{GS} = 0 V.$

T_{amb} = 25 °C.

Fig 17. Common-source forward transfer admittance; typical values.



8. Package outline

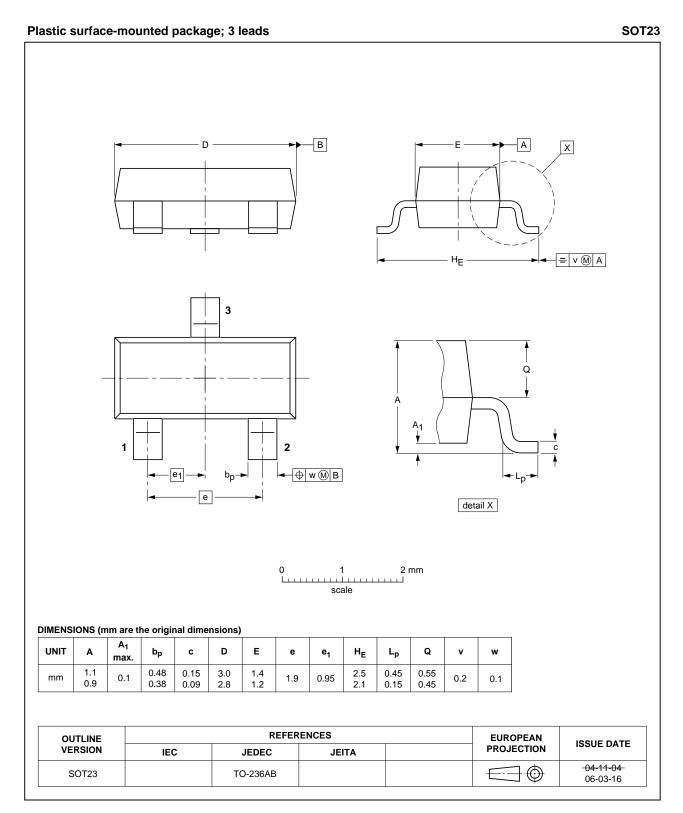


Fig 19. Package outline

9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BF861A_BF861B_BF861C v.5	20110915	Product data sheet	-	BF861A_BF861B_BF861C v.4
Modifications:		of this data sheet has be of NXP Semiconductors.	•	comply with the new identity
	 Legal texts 	have been adapted to th	ne new company r	ame where appropriate.
	 Package ou 	ıtline drawings have bee	n updated to the I	atest version.
BF861A_BF861B_BF861C v.4 (9397 750 13395)	20040924	Product data sheet	-	BF861 v.3
BF861 v.3 (9397 750 02667)	19970904	Product specification	-	BF861 v.2
BF861 v.2	19950414	-	-	BF861 v.1
BF861 v.1	19940829	-	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions"
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